FIS GAS SENSOR SB-19-00

for HYDROGEN DETECTION

The SB-19-00is a tin dioxide semiconductor gas sensor which has an excellent sensitivity and selectivity to hydrogen. Significant low power consumption design (120mW) is advantageous for portable gas detection devices.

Structure

Gas sensitive semiconductor material is a mini bead type and a heater coil and electrode wire are embedded in the element. The sensing element is installed in the metal housing which uses double stainless steel mesh (100 mesh) in the path of gas flow. The mesh is an anti-explosion feature (Fig1b).

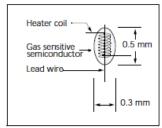


Fig 1a. Sensing element

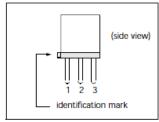


Fig 1c. Pin Layout

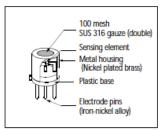


Fig 1b. Configuration

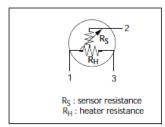


Fig 1d. Equivalent circuit

Operating conditions

Fig 2 shows the standard operating circuit for this model. The change of the sensor resistance (Rs) is obtained as the change of the output voltage across the fixed or variable resistor (RL). In order to obtain the best performance and specified characteristics, the values of the heater voltage (VH) circuit voltage (VC) and load resistance (RL) must be within the range of values given in the standard operating conditions shown in the Specification table on the next page.

Sensitivity characteristics

Fig 3 shows the sensitivity characteristics curves of the SB-19 (typical data). Sensitivity characteristics of our gas sensors are expressed by the relationship between the sensor resistance and gas concentration. The sensor resistance decreases with an increase of gas concentration based on a logarithmic function.

The sensitivity characteristics of the SB-19-00 is specified by the following parameters.

- Sensor resistance level: at 100 ppm of hydrogen
- Sensor resistance change ratio: between hydrogen 100ppm and 1000 ppm

See the specification table on the next page for further details.

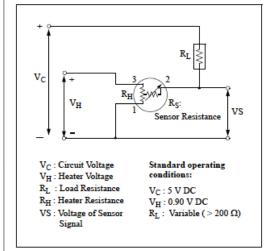


Fig 2. Standard circuit

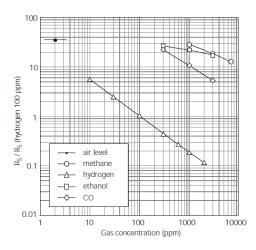


Fig3. Sensitivity characteristics

SPECIFICATIONS



Specifications: SB-19-00

A. Standard Operating conditions

Symbol	Parameter	Specification	Conditions etc.
VH	Heater voltage	0.9 V ± 0.05 V	AC, DC or pulse
VC	Circuit voltage	Less than 5 V	DC: Pin2 (+) - Pin 1 (-)
RL	Load resistance	Variable (> 200 Ω)	P _S < 10 mW
RH	Heater resistance	$2.8 \Omega \pm 0.2 \Omega$	at room temperature
IH	Heater current	130 mA (Typical value)	IH = VH / RH
PH	Heater power consumption	120 mW (Typical value)	PH = VH ² / RH
PS	Power dissipation of sensing element	Less than 10mW	$P_{S} = \frac{(VC-VRL)^2}{R}$

B. Environmental conditions

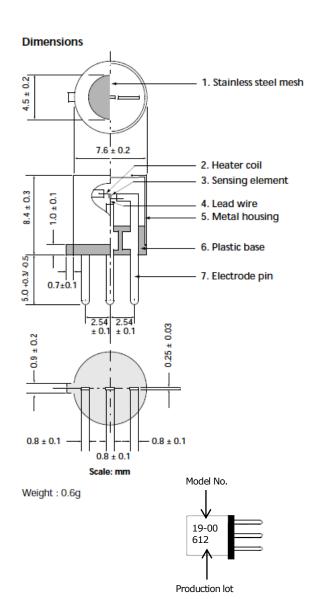
Symbol	Parameter	Specification	Conditions etc.
Tao	Operating temperature	-10 °C to 50 °C	
Tas	Storage temp	-20 °C to 60 °C	
RH	Relative humidity	Less than 95%RH	
(O ₂)	Oxygen concentration	21% ± 1% (Standard condition)	Absolute minimum level : more than 18%.
		The sensitivity characteristics are influenced by the variation in oxygen concentration. Please consult us for details.	

C. Sensitivity characteristics

Model	SB-19-00		
Symbol	Parameter	Specification	Conditions etc.
Rs	Sensor resistance	0.2k to 2kΩ	at 100 ppm of hydrogen
а	Sensitivity	0.6 to 1.2	log(Rs(1000ppm)/Rs(100ppm) log(1000ppm/100ppm)
Temp : 20° Standard Test Conditions: Humidity : (in clean a Pre-heatin			

D. Mechanical characteristics

Items	Conditions	Specifications
Vibration	Frequency : 5 - 500 Hz Acceleration : 1.3 G Sweep Time : 40 min.	Should satisfy the specifications shown in the
Drop	Height: 60 cm Number of impacts: 3 times	sensitivity characteristics after test.



E. Parts and Materials

No.	Parts	Materials	
1	Stainless steel mesh	SUS 316 (100 mesh, double)	
2	Heater coil	Platinum	
3	Sensing element	Tin dioxide	
4	Lead wire	Platinum	
5	Metal housing	Nickel plated brass	
6	Plastic base	PBT (GF30%)	
7	Electrode pin	Iron-nickel alloy	

Please contact OCTOBER, 2018

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In the interest of continued product improvement, we reserve the right to change design features without prior notice.